







SN54AHCT126, SN74AHCT126

DECEMBER 1995 - REVISED MAY 2023

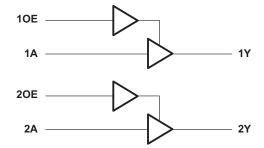
SNx4AHCT126 Quadruple Bus Buffer Gates With 3-State Outputs

1 Features

- Inputs are TTL-voltage compatible
- Latch-up performance exceeds 250 mA per JESD 17
- ESD protection exceeds JESD 22:
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
- On products compliant to MIL-PRF-38535, All parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

2 Applications

- Servers
- PCs and notebooks
- **Network switches**
- Wearable health and fitness devices
- Telecom infrastructures
- Electronic points-of-sale



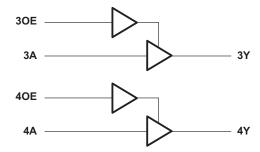
3 Description

The SNxAHCT126 devices are quadruple-bus buffer gates featuring independent line drivers with 3-state outputs.

Device Information

PART NUMBER	RATING	PACKAGE SIZE(1)
		D (SOIC, 14)
SN54AHCT126	Military	DB (SSOP, 14)
		DGV (TVSOP, 14)
		NS (PDIP, 14)
		N (SOP, 14)
		PW (TSSOP, 14)
SN74AHCT126	Commercial	J (CDIP, 14)
		W (CFP, 14)
		BQA (WQFN, 14)
		FK (LCCC, 20)

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



Table of Contents

1 Features	8 Detailed D	escription	10
2 Applications		ew	
3 Description	8.2 Function	onal Block Diagram	10
4 Revision History		e Description	
5 Pin Configuration and Functions		Functional Modes	
6 Specifications	9 Applicatio	n and Implementation	11
6.1 Absolute Maximum Ratings	9.1 Applica	ation Information	11
6.2 ESD Ratings		l Application	
6.3 Recommended Operating Conditions	9.3 Power	Supply Recommendations	12
6.4 Thermal Information	9.4 Layout		12
6.5 Electrical Characteristics	10 Device ar	nd Documentation Support	13
6.6 Switching Characteristics, V _{CC} = 5 V ± 0.5 V	10.1 Recei	iving Notification of Documentation Upo	dates13
6.7 Noise Characteristics	10.2 Suppo	ort Resources	13
6.8 Operating Characteristics	10.3 Trade	emarks	13
6.9 Typical Characteristics	10.4 Electr	ostatic Discharge Caution	13
7 Parameter Measurement Information	10.5 Gloss	sary	13
		·	
4 B - 1-1 111-1			

4 Revision History

N	OTE: Page numbers for previous revisions may differ from page numbers in the current version.	
С	hanges from Revision P (August 2014) to Revision Q (May 2023)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Added the BQA package information throughout the document	1
С	hanges from Revision O (July 2003) to Revision P (August 2014)	Page
•	Updated document to new TI data sheet standards	1
•	Deleted Ordering Information Table	1
•	Added Military Disclaimer to Features list	1
•	Added Applications	1
•	Added Pin Functions table	
•	Added Handling Ratings table	
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	<mark>5</mark>
•	Added Thermal Information table	6
•	Added –40°C to 125°C for SN74AHCT126 in Electrical Characteristics table	<u>6</u>
•	Added –40°C to 125°C for SN74AHCT126 in the Switching Characteristics table	<mark>7</mark>
•	Added Typical Characteristics	
•	Added Application and Implementation section	11
•	Added Power Supply Recommendations and Layout sections	



5 Pin Configuration and Functions

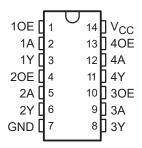
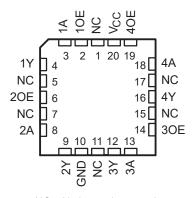


Figure 5-1. SN54AHCT126 J or W Packages, CDIP or CFP SN74AHCT126 D, DB, DGV, N, NS, or PW Packages, 14-Pin SOIC, SSOP, TVSOP, PDIP, SOP or TSSOP (Top View)



NC - No internal connection

Figure 5-2. SN54AHCT126 FK Package, 20-Pin LCCC (Top View)

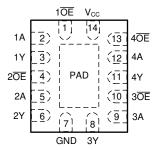


Figure 5-3. SNx4AHCT126 BQA Package, 14-Pin WQFN (Top View)

Table 5-1. Pin Functions

	PIN				
	SN74AHCT126	SN54A	HCT126	TYPE ⁽¹⁾	DESCRIPTION
NAME	D, DB, DGV, N, NS, PW, BQA	J, W	FK] <u>-</u>	2230.W 113.W
1A	2	2	3	ı	1A Input
10E	1	1	2	I	Output Enable 1
1Y	3	3	4	0	1Y Output
2A	5	5	8	I	2A Input
20E	4	4	6	I	Output Enable 2
2Y	6	6	9	0	2Y Output
ЗА	9	9	13	I	3A Input
3OE	10	10	14	I	Output Enable 3
3Y	8	8	12	0	3Y Output
4A	12	12	18	I	4A Input
40E	13	13	19	I	Output Enable 4
4Y	11	11	16	0	4Y Output
GND	7	7	10	_	Ground Pin



Table 5-1. Pin Functions (continued)

	PIN			(0	
	SN74AHCT126	SN54Al	HCT126	TYPE ⁽¹⁾	DESCRIPTION
NAME	D, DB, DGV, N, NS, PW, BQA	J, W	FK	· · · · <u>-</u>	5-551 1151.
			1		
			5		
NC		_	7		No Connection
110			11		TWO CONTRICTIONS
			15		
			17		
V _{CC}	14	14	20	_	Power Pin
Thermal Pag	J (2)			_	Thermal Pad

⁽¹⁾ I = input, O = output(2) For BQA package only

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Output voltage range ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±25	mA
	Continuous current through V _{CC} or GND			±50	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	e	-65	150	ů
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(2)

		SN54AHCT	126 ⁽¹⁾	SN74AHCT126		UNIT
		MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V _{IH}	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	V _{CC}	0	V _{CC}	V
I _{OH}	High-level output current		-8		-8	mA
I _{OL}	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
T _A	Operating free-air temperature	-55	125	-40	125	°C

Product Preview.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI Application Report, Implications of Slow or Floating CMOS Inputs (SCBA004).



6.4 Thermal Information

		SN74AHCT126								
	THERMAL METRIC ⁽¹⁾	D	DB	DGV	N	NS	PW	BQA	UNIT	
		14 PINS								
R _{0JA}	Junction-to-ambient thermal resistance	90.6	107.1	129.0	57.4	90.7	122.6	88.3		
R _{0JC(top)}	Junction-to-case (top) thermal resistance	50.9	59.6	52.1	44.9	48.3	51.4	90.9		
R _{0JB}	Junction-to-board thermal resistance	44.8	54.4	62.0	37.2	49.4	64.4	56.8		
ΨЈТ	Junction-to-top characterization parameter	14.7	20.5	6.5	30.1	14.6	6.7	9.9	°C/W	
ΨЈВ	Junction-to-board characterization parameter	44.5	53.8	61.3	37.1	49.1	63.8	56.7		
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a	33.4		

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C		SN54AHCT126		SN74AHCT126		SN74AHCT126 -40 to 125°C		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
\/	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		4.4		V
V_{OH}	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		3.8		V
\/	I _{OL} = 50 μA	4.5 V			0.1	-	0.1		0.1		0.1	V
V _{OL}	I _{OL} = 8 mA				0.36	-	0.44		0.44		0.44	V
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μΑ
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5		±2.5		±2.5	μΑ
I _{CC}	$V_1 = V_{CC}$ or GND $I_0 = 0$	5.5 V			2		20		20		20	μΑ
ΔI _{CC} ⁽²⁾	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		4	10				10			pF
C _o	V _O = V _{CC} or GND	5 V		15								pF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

⁽²⁾ This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.



6.6 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (OUTPUT)	TO (INPUT)	LOAD CAPACITANCE	T	T _A = 25°C			SN54AHCT126 -55°C to 125°C		CT126 85°C	SN74AHCT126 -40°C to 125°C		UNIT			
	(001701)	(INFOI)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX				
t _{PLH}	- A	Υ	C = 15 pE		3.8(1)	5.5 ⁽¹⁾	1 ⁽¹⁾	6.5 ⁽¹⁾	1	6.5	1	7	no			
t _{PHL}		T T	C _L = 15 pF		3.8(1)	5.5 ⁽¹⁾	1 ⁽¹⁾	6.5 ⁽¹⁾	1	6.5	1	7	ns			
t _{PZH}	OE	Υ	C _I = 15 pF		3.6 ⁽¹⁾	5.1 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	6.5	ns			
t _{PZL}	OE T	OE Y	CL = 15 pr		3.6 ⁽¹⁾	5.1 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	6.5	115			
t _{PHZ}	OE	Y	C _I = 15 pF		4.6(1)	6.8 ⁽¹⁾	1 ⁽¹⁾	8(1)	1	8	1	8.5	ns			
t _{PLZ}			GL = 15 pF		4.6 ⁽¹⁾	6.8 ⁽¹⁾	1 ⁽¹⁾	8(1)	1	8	1	8.5	113			
t _{PLH}	А		Y	V		C = 50 pF		5.3	7.5	1	8.5	1	8.5	1	9.5	ns
t _{PHL}	A	T T	$C_L = 50 pF$		5.3	7.5	1	8.5	1	8.5	1	9.5	115			
t _{PZH}	OE	Y	C _I = 50 pF		5.1	7.1	1	8	1	8	1	9				
t _{PZL}		T T	C _L = 50 pr		5.1	7.1	1	8	1	8	1	9	ns			
t _{PHZ}	OE Y	0 - 50 - 5		6.1	8.8	1	10	1	10	1	11					
t _{PLZ}		OE Y	Y $C_L = 50 \text{ pF}$		6.1	8.8	1	10	1	10	1	11	ns			
t _{sk(o)}			C _L = 50 pF			1(2)				1		1	ns			

- (1) On products compliant to MIL-PRF-38535, this parameter is not production tested.
- (2) On products compliant to MIL-PRF-38535, this parameter does not apply.

6.7 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

	PARAMETER	SN74AHCT12	UNIT	
	PARAMETER	MIN	MAX 0.8 -0.8	ONT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	4.4		V
V _{IH(D)}	High-level dynamic input voltage	2		V
V _{IL(D)}	Low-level dynamic input voltage		0.8	V

⁽¹⁾ Characteristics are for surface-mount packages only.

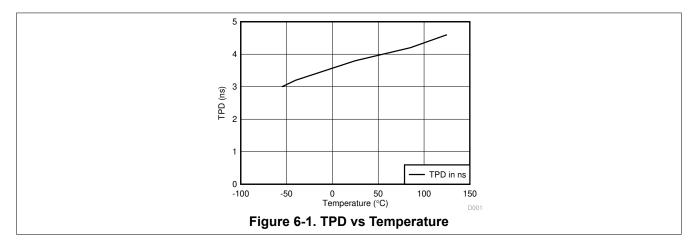
6.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_{A} = 25^{\circ}\text{C}$

PARAMETER		TEST (CONDITIONS	TYP	UNIT	ı
C _{pd} Power dissipation capacitance		No load,	f = 1 MHz	14	pF	

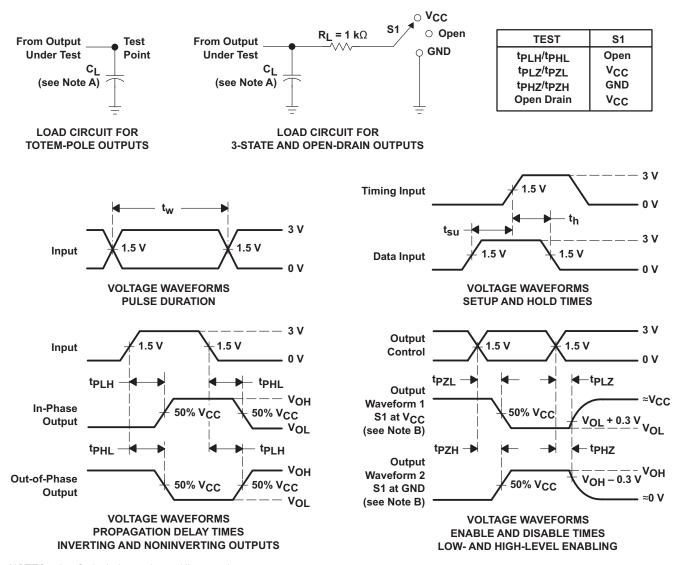


6.9 Typical Characteristics





7 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage and Waveforms



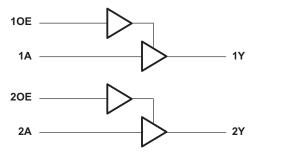
8 Detailed Description

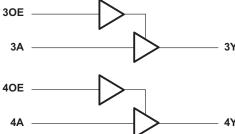
8.1 Overview

The SNxAHCT126 devices are quadruple-bus buffer gates featuring independent line drivers with 3-state outputs.

Each output is disabled when the associated output-enable (OE) input is low. When OE is high, the respective gate passes the data from the A input to the Y output. For the high-impedance state during power up or power down, tie OE to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

8.2 Functional Block Diagram





8.3 Feature Description

- · TTL inputs
 - Lowered switching threshold allows up translation from 3.3 V to 5 V
- Slow edges reduce output ringing

8.4 Device Functional Modes

Table 8-1. Function Table (Each Buffer)

INI	PUTS	OUTPUT
OE	Α	Y
Н	Н	Н
Н	L	L
L	X	Z



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SNx4AHCT126 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of $0.8\text{-V}\ V_{\text{IL}}$ and $2\text{-V}\ V_{\text{IH}}$. This feature makes it ideal for translating up from $3.3\ V$ to $5\ V$. Figure 9-2 shows this type of translation.

9.2 Typical Application

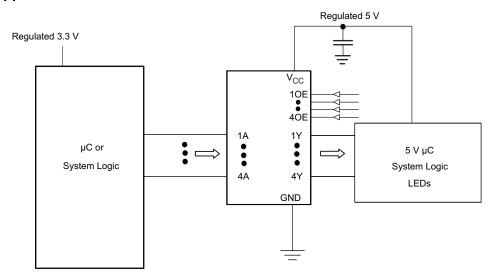


Figure 9-1. Typical Application Schematic

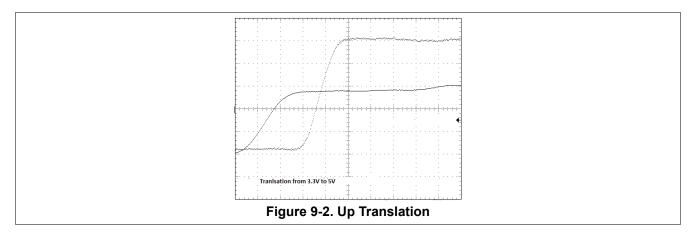
9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended input conditions:
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified High and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}
- 2. Recommended output conditions:
 - Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}

9.2.3 Application Curves



9.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} pins, 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

9.4 Layout

9.4.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 9-3 shows the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} ; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IO's so they cannot float when disabled.

9.4.2 Layout Example

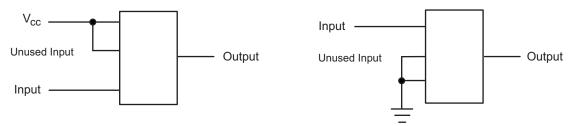


Figure 9-3. Layout Diagram



10 Device and Documentation Support

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 8-Sep-2023

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9686301QDA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686301QD A SNJ54AHCT126W	Samples
SN74AHCT126BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHT126	Samples
SN74AHCT126D	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHCT126	
SN74AHCT126DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB126	Samples
SN74AHCT126DG4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT126	
SN74AHCT126DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB126	Samples
SN74AHCT126DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT126	Samples
SN74AHCT126N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT126N	Samples
SN74AHCT126NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT126	Samples
SN74AHCT126PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB126	Samples
SNJ54AHCT126W	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686301QD A SNJ54AHCT126W	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



www.ti.com 8-Sep-2023

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54AHCT126, SN74AHCT126:

Catalog: SN74AHCT126

Automotive: SN74AHCT126-Q1, SN74AHCT126-Q1

Enhanced Product: SN74AHCT126-EP, SN74AHCT126-EP

Military: SN54AHCT126

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

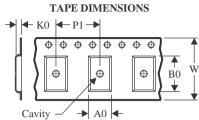
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2023

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

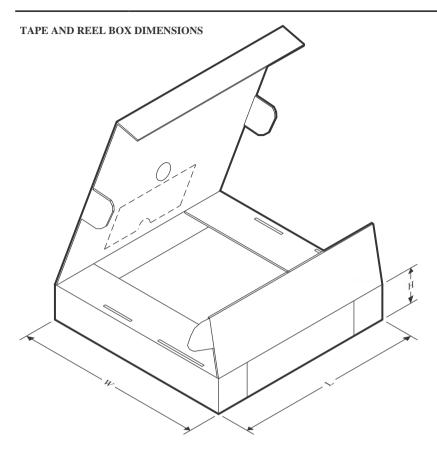


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT126BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74AHCT126DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHCT126DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHCT126DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHCT126NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHCT126PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 3-Jun-2023



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT126BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74AHCT126DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHCT126DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHCT126DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AHCT126NSR	SO	NS	14	2000	367.0	367.0	38.0
SN74AHCT126PWR	TSSOP	PW	14	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2023

TUBE



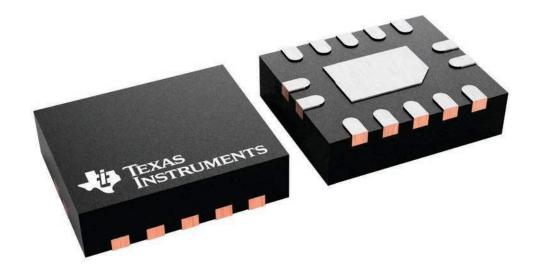
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9686301QDA	W	CFP	14	1	506.98	26.16	6220	NA
SN74AHCT126D	D	SOIC	14	50	506.6	8	3940	4.32
SN74AHCT126DG4	D	SOIC	14	50	506.6	8	3940	4.32
SN74AHCT126N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHCT126N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AHCT126W	W	CFP	14	1	506.98	26.16	6220	NA

2.5 x 3, 0.5 mm pitch

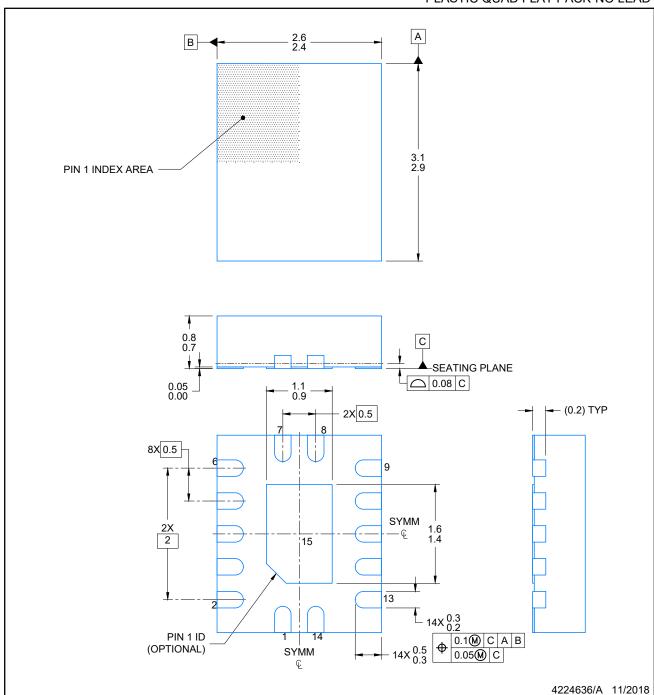
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

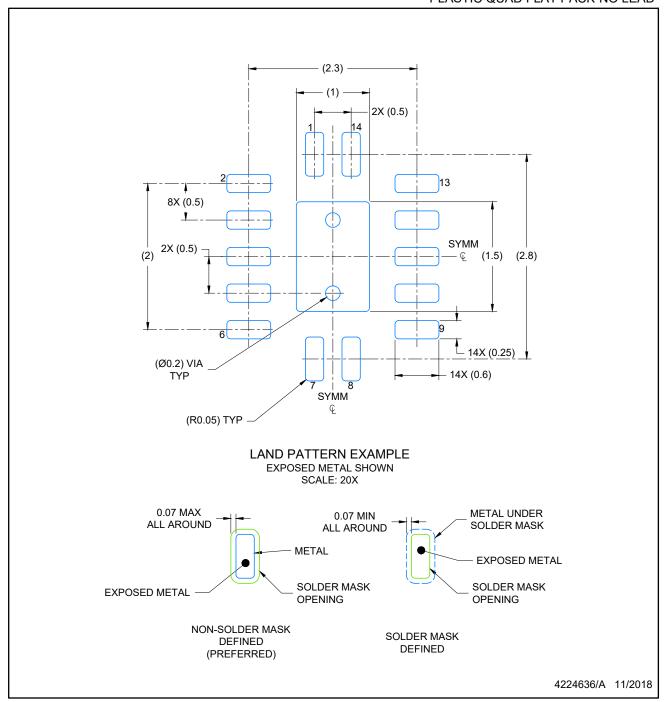
PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD

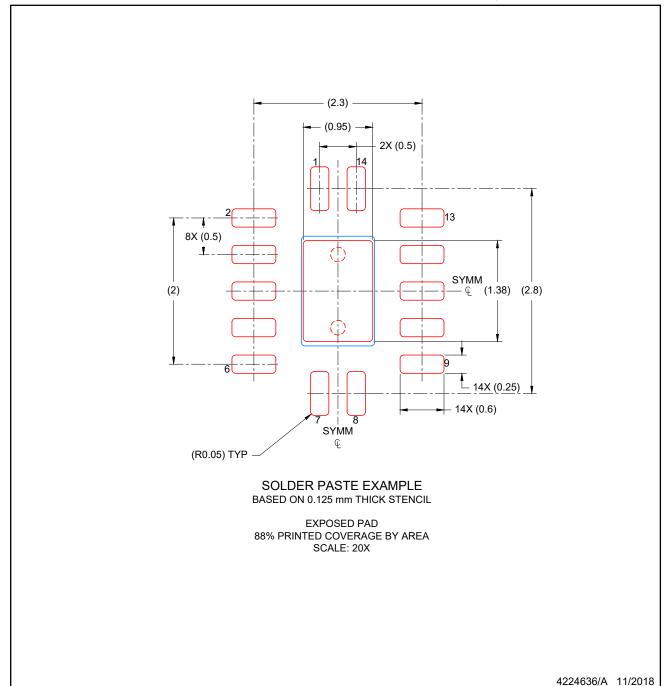


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated